# NSN 5961-00-257-1020

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-257-1020

## Inclosure Material:

Metal

**Overall Length:** 

0.260 inches

## Terminal Length:

1.500 inches

## **Overall Diameter:**

0.370 inches

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-39

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Terminal

**Terminal Circle Diameter:** 0.200 inches

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

250.0 breakdown voltage, collector-to-base, emitter open and 250.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

0.50 amperes source cutoff current

#### **Power Rating Per Characteristic:**

1.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

## **Terminal Type And Quantity:**

3 uninsulated wire lead

## Shelf Life:

N/a

Unit Of Measure:

---

#### Demilitarization:

No

Fiig:

A110a0